

v05.1211

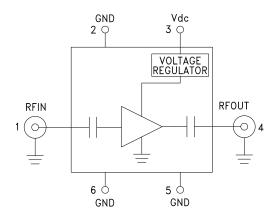


## **Typical Applications**

The HMC-C045 LNA is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- · Military & Space
- Test Instrumentation

### **Functional Diagram**



## LOW NOISE AMPLIFIER MODULE, 1.8 - 4.2 GHz

#### **Features**

Noise Figure: 1.2 dB @ 2.4 GHz

Gain: 26 dB OIP3: +26 dBm

P1dB Output Power: +15.5 dBm 50 Ohm Matched Input/Output Hermetically Sealed Module

Field Replaceable SMA Connectors

-55 °C to +85 °C Operating Temperature

### **General Description**

The HMC-C045 is a GaAs MMIC pHEMT Low Noise Amplifier in a miniature, hermetic module which operates between 1.8 and 4.2 GHz. This high dynamic range low noise amplifier module provides 26 dB of gain, sub-2 dB noise figure and up to +26 dBm of output IP3 while operating from a single positive supply between +8V and +15V. The amplifier I/Os are internally matched to 50 Ohms and DC blocked for robust performance. The module features removable coaxial connectors which can be detached to allow direct connection of the I/O pins to a microstrip or coplanar circuit.

## Electrical Specifications, $T_A = +25^{\circ}$ C, Vdc = +12V

Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range		1.8 - 4.2			2.0 - 3.8		GHz
Gain	23	26		23	26		dB
Gain Variation Over Temperature		0.03	0.05		0.03	0.05	dB/ °C
Noise Figure		1.2	2.5		1.2	2.0	dB
Input Return Loss		13			13		dB
Output Return Loss		13			13		dB
Output Power for 1 dB Compression (P1dB)	12.5	15.5		12.5	15.5		dBm
Saturated Output Power (Psat)		17.5			17.5		dBm
Output Third Order Intercept (IP3)		26			26		dBm
Supply Current		105	140		105	140	mA

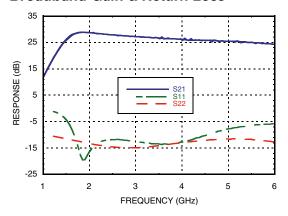


v05.1211

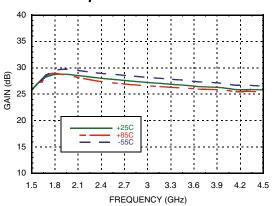


# LOW NOISE AMPLIFIER MODULE, 1.8 - 4.2 GHz

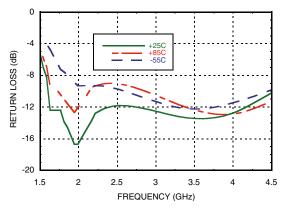
#### **Broadband Gain & Return Loss**



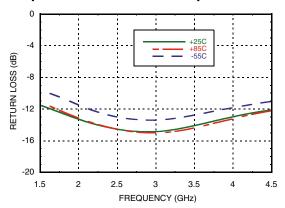
### Gain vs. Temperature



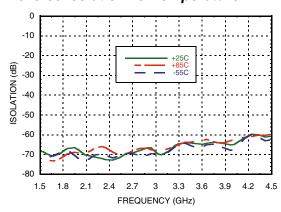
### Input Return Loss vs. Temperature



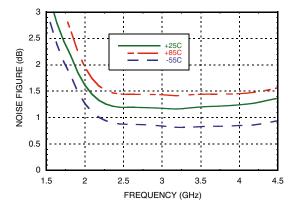
### Output Return Loss vs. Temperature



#### Reverse Isolation vs. Temperature



### Noise Figure vs. Temperature

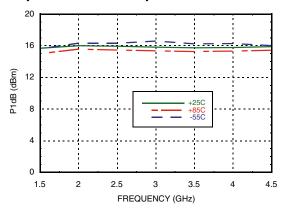




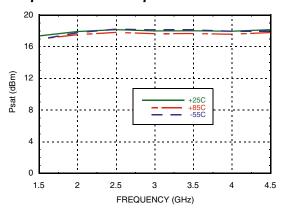


## LOW NOISE AMPLIFIER MODULE, 1.8 - 4.2 GHz

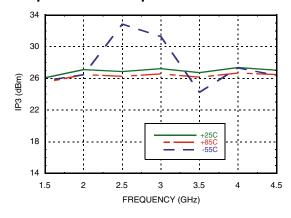
### Output P1dB vs. Temperature



### Output Psat vs. Temperature



#### Output IP3 vs. Temperature



### **Absolute Maximum Ratings**

Bias Supply Voltage (Vdc)	+15 Vdc	
RF Input Power (RFIN)	+0 dBm	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-55 to +85 °C	





v05.1211



# LOW NOISE AMPLIFIER MODULE, 1.8 - 4.2 GHz

### **Pin Descriptions**

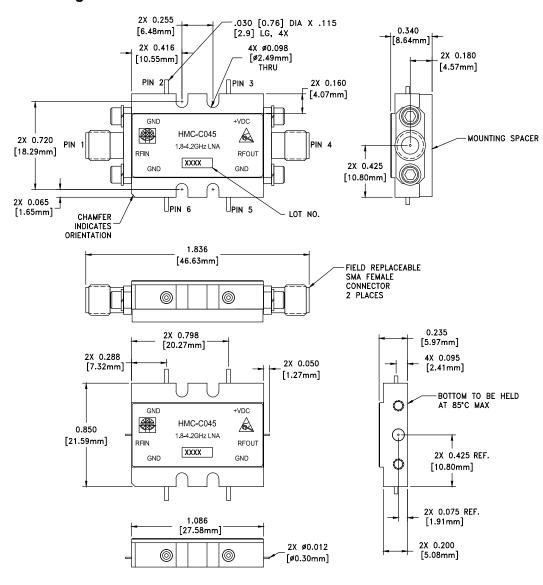
Pin Number	Function	Description	Interface Schematic	
1	RFIN & RF Ground	RF input connector, coaxial female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	RFINO—  -	
2, 5, 6	GND	One of these pins must be connected to power supply ground.	ĢGND <u>=</u>	
3	Vdc	Power supply voltage for the amplifier.	Vdc O VOLTAGE REGULATOR =	
4	RFOUT & RF Ground	RF output connector, coaxial female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	→ ⊢ ○ RFOUT	





## LOW NOISE AMPLIFIER MODULE, 1.8 - 4.2 GHz

### **Outline Drawing**



VIEW SHOWN WITH CONNECTORS AND MOUNTING SPACER REMOVED

### Package Information

Package Type	C-10
Package Weight [1]	18.7 gms <sup>[2]</sup>
Spacer Weight	3.3 gms <sup>[2]</sup>

[1] Includes the connectors

[2] ±1 gms Tolerance

#### NOTES:

- 1. PACKAGE, LEADS, COVER MATERIAL: KOVAR $^{\text{TM}}$
- 2. FINISH: GOLD PLATE OVER NICKEL PLATE
- 3. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 4. TOLERANCES:
- 4.1 .XX = ±0.02
- $4.2.XXX = \pm 0.010$
- 5. FIELD REPLACEABLE SMA CONNECTORS

**ANALOG**DEVICES



Notes:

LOW NOISE AMPLIFIER MODULE, 1.8 - 4.2 GHz